### HFA04TB60SPbF

### Vishay High Power Products

# HEXFRED® Ultrafast Soft Recovery Diode, 4 A



| <b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |                 |   |              |      |      |      |       |
|--|-----------------|---|--------------|------|------|------|-------|
| PARAMETER  | SYMBOL          | TEST CONDITIONS                                 |              | MIN. | TYP. | MAX. | UNITS |
| Cathode to anode breakdown voltage   | V <sub>BR</sub> | Ι <sub>R</sub> = 100 μΑ                         |              | 600  | -    | -    |       |
| Maximum forward voltage  |                 | I <sub>F</sub> = 4.0 A                          | See fig. 1 - | 1.5  | 1.8  | V    |       |
|  | V <sub>FM</sub> | I <sub>F</sub> = 8.0 A                          |              | -    | 1.8  | 2.2  | _     |
|  |                 | I <sub>F</sub> = 4.0 A, T <sub>J</sub> = 125 °C |              | -    | 1.4  | 1.7  |       |
| Maximum reverse<br>leakage current   | I <sub>RM</sub> | V <sub>R</sub> = V <sub>R</sub> rated           | See fig. 2   | -    | 0.17 | 3.0  | μΑ    |
|  |                 | $T_J = 125$ °C, $V_R = 0.8 \times V_R$ rated    |              | -    | 44   | 300  |       |
| Junction capacitance   | C <sub>T</sub>  | V <sub>R</sub> = 200 V                          | See fig. 3   | -    | 4.0  | 8.0  | pF    |
| Series inductance  | L <sub>S</sub>  | Measured lead to lead 5 mm from package body -  |              | -    | 8.0  | -    | nH    |

| <b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |                           |  |  |      |      |      |        |
|---|---------------------------|--|--|------|------|------|--------|
| PARAMETER   | SYMBOL                    | TEST CONDITIONS                                |  | MIN. | TYP. | MAX. | UNITS  |
| Reverse recovery time<br>See fig. 5, 6  | t <sub>rr</sub>           | $I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A}$ | Vμs, V <sub>R</sub> = 30 V   | -    | 17   | -    | ns     |
|   | t <sub>rr1</sub>          | T <sub>J</sub> = 25 °C                         | I <sub>F</sub> = 4.0 A<br>dI <sub>F</sub> /dt = 200 A/μs<br>V <sub>R</sub> = 200 V | -    | 28   | 42   |        |
|   | t <sub>rr2</sub>          | T <sub>J</sub> = 125 °C                        |  | -    | 38   | 57   |        |
| Peak recovery current   | I <sub>RRM1</sub>         | T <sub>J</sub> = 25 °C                         |  | -    | 2.9  | 5.2  | Α      |
|   | I <sub>RRM2</sub>         | T <sub>J</sub> = 125 °C                        |  | -    | 3.7  | 6.7  |        |
| Reverse recovery charge<br>See fig. 7   | Q <sub>rr1</sub>          | T <sub>J</sub> = 25 °C                         |  | -    | 40   | 60   | nC     |
|   | Q <sub>rr2</sub>          | T <sub>J</sub> = 125 °C                        |  | -    | 70   | 105  |        |
| Peak rate of fall of recovery current during $t_{\mbox{\scriptsize b}}$ See fig. 8          | dI <sub>(rec)M</sub> /dt1 | T <sub>J</sub> = 25 °C                         |  | -    | 280  | -    | - A/μs |
|   | dI <sub>(rec)M</sub> /dt2 | T <sub>J</sub> = 125 °C                        |  | -    | 235  | -    |        |

| THERMAL - MECHANICAL SPECIFICATIONS     |                   |                                    |            |      |      |       |
|---|-------------------|------------------------------------|------------|------|------|-------|
| PARAMETER                               | SYMBOL            | /MBOL TEST CONDITIONS              |            | TYP. | MAX. | UNITS |
| Lead temperature                        | T <sub>lead</sub> | 0.063" from case (1.6 mm) for 10 s | -          | -    | 300  | °C    |
| Thermal resistance, junction to case    | R <sub>thJC</sub> |                                    | -          | -    | 5.0  | K/W   |
| Thermal resistance, junction to ambient | R <sub>thJA</sub> | Typical socket mount               | -          | -    | 80   | R/ VV |
| Weight                                  |                   |                                    | -          | 2.0  | -    | g     |
|   |                   |                                    | -          | 0.07 | -    | oz.   |
| Marking device                          |                   | Case style D <sup>2</sup> PAK      | HFA04TB60S |      |      |       |

Document Number: 94036 Revision: 02-Sep-09



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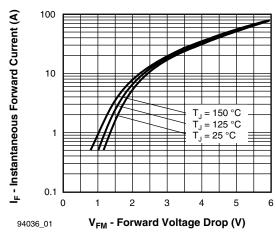


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current

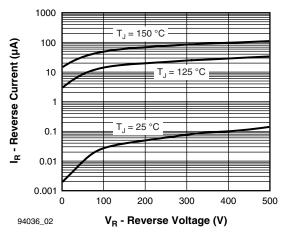


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

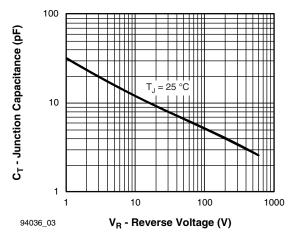


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

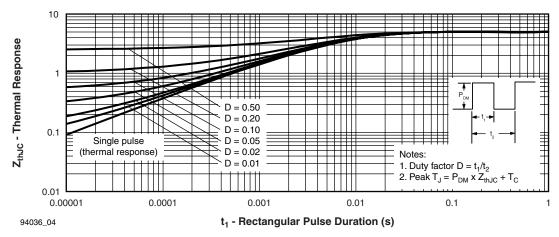


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

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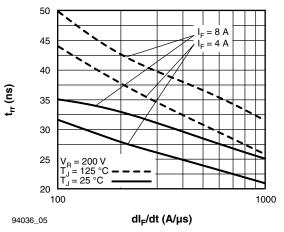


Fig. 5 - Typical Reverse Recovery Time vs. dI<sub>F</sub>/dt

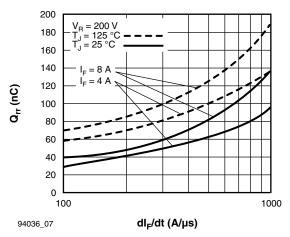


Fig. 7 - Typical Stored Charge vs. dI<sub>F</sub>/dt

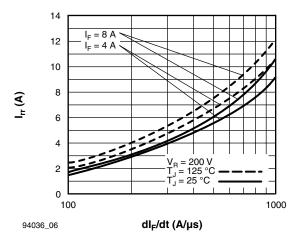


Fig. 6 - Typical Recovery Current vs.  $dI_F/dt$ 

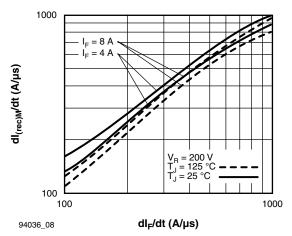


Fig. 8 - Typical  $dl_{(rec)M}/dt$  vs.  $dl_F/dt$ 



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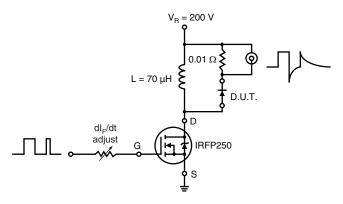
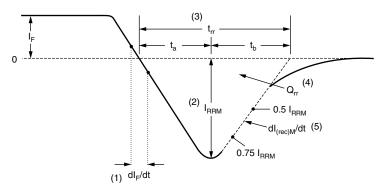


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1)  $dl_F/dt$  rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3)  $t_{\rm rr}$  reverse recovery time measured from zero crossing point of negative going  $I_{\rm F}$  to point where a line passing through 0.75  $I_{\rm RRM}$  and 0.50  $I_{\rm RRM}$  extrapolated to zero current.
- (4)  $\mathbf{Q}_{rr}$  area under curve defined by  $\mathbf{t}_{rr}$  and  $\mathbf{I}_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5)  $dI_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 10 - Reverse Recovery Waveform and Definitions

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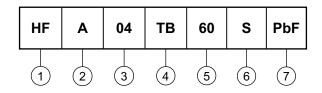
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#### **ORDERING INFORMATION TABLE**

Device code



1 - HEXFRED® family

Process designator: A = Subs. electron irradiated

B = Subs. platinum

**3** - Current rating (04 = 4 A)

- Package outline (TB = TO-220, 2 leads)

Voltage rating (60 = 600 V)

6 - Configuration (S = SMD)

7 - • None = Standard production

• PbF = Lead (Pb)-free

| LINKS TO RELATED DOCUMENTS |                          |  |  |  |  |
|----------------------------|--------------------------|--|--|--|--|
| Dimensions                 | www.vishay.com/doc?95046 |  |  |  |  |
| Part marking information   | www.vishay.com/doc?95054 |  |  |  |  |
| Packaging information      | www.vishay.com/doc?95032 |  |  |  |  |

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For technical questions, contact: diodestech@vishay.com

Document Number: 94036 Revision: 02-Sep-09



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Document Number: 91000
Revision: 18-Jul-08
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